

200CMQ SERIES

Technical Data Data Sheet N1184, Rev. B **Green Products**

200CMQ035/200CMQ040/200CMQ045 SCHOTTKY RECTIFIER

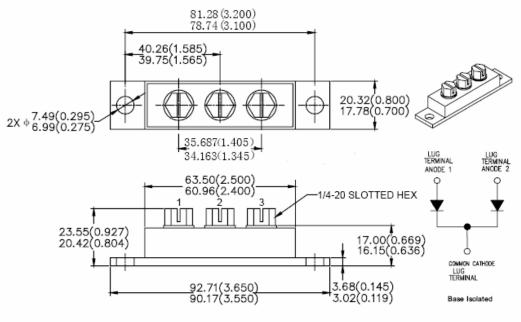
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection
 Converters
 UPS System
 Welding

Features:

- 150 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2 Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)

MARKING,MOLDING RESIN Marking for 200CMQ035/040/045, 1st row SS YYWWL, 2nd row 200CMQ035/040/045 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin Epoxy resin UL:94V-0

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SANGDEST **MICROELECTRONICS**

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units	
Peak Inverse Voltage	V _{RWM}	-	35	200CMQ035	V	
			40	200CMQ040		
			45	200CMQ045		
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =114°C,	100	per leg	А	
		rectangular wave form	200	per device		
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	1860		A	
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =20A,L=0.67mH	135		mJ	
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A =1.5× V _R typical	20		A	

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V _{F1}	@ 100A, Pulse, T _J = 25 °C @ 200A, Pulse, T _J = 25 °C	0.54 0.68	V
	V _{F2}	@ 100A, Pulse, T _J = 125 °C	0.49	V
		@ 200A, Pulse, T _J = 125 °C	0.64	
Max. Reverse Current (per leg) *	I _{R1} I _{R2}	$@V_R = rated V_R T_J = 25 °C$ $@V_R = rated V_R T_J = 125 °C$	<u> </u>	mA mA
Max. Junction Capacitance (per leg)	CT	$@V_R = 5V, T_C = 25 \circ C$ $f_{SIG} = 1MHz$	5200	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

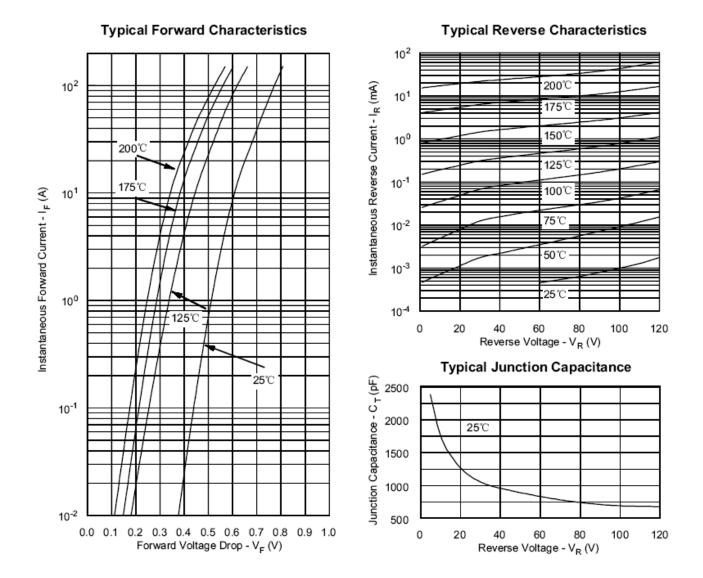
Characteristics	Symbol	Condition	Specifi	Units		
Max. Junction Temperature	TJ	-	-55 to	°C		
Max. Storage Temperature	T _{stg}	-	-55 to	°C		
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.70		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.35		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ ext{ heta}cs}$	Mounting surface, smooth and greased	0.10		°C/W	
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	79		g	
Case Style	PRM4 Isolated					

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